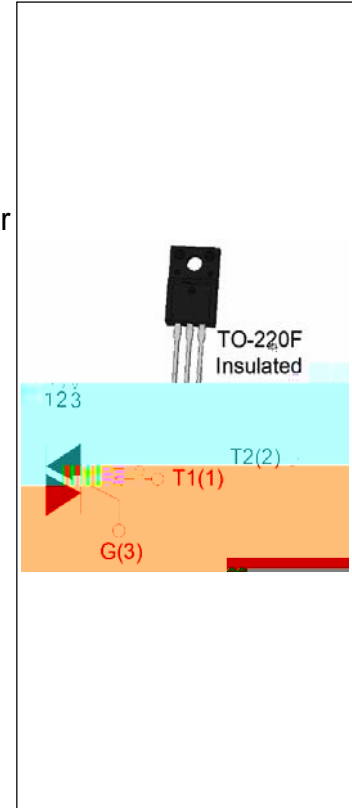


## JST16F-1000CW 16A TRIAC

Rev.A.1.1

### DESCRIPTION:

The JST16F-1000CW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST16F-1000CW snubberless triac is especially recommended for use on inductive loads. By using an external plastic package, JST16F-1000CW provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.



### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	1000	V
$I_{GT} / /$	35/35/35	mA

### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	1000	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	1000	V
RMS on-state current ( $T_c 073^\circ\text{C}$ )	$I_{T(RMS)}$	16	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	160	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		176	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	128	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2\text{hI}_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$di/dt$	100	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{G(AV)}$	0.5	W

Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	4	kV

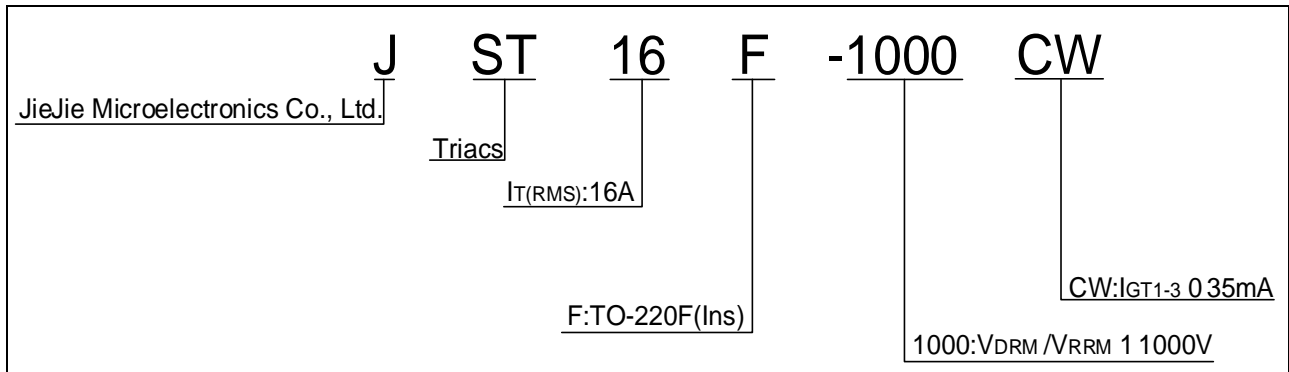
**ELECTRICAL CHARACTERISTICS** ( $T_j=25$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33$	- -	MAX.	35	mA
$V_{GT}$		- -	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=125$ $R_L=3.3k$	- -	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	-	MAX.	50	mA
				60	
$I_H$	$I_T=500mA$		MAX.	40	mA
dV/dt	$V_D=670V$ Gate Open $T_j=125$		MIN.	800	V/ $\mu s$
(dI/dt)c	(dV/dt)c=20V/ $\mu s$ $T_j=125$		MIN.	10	A/ms
$t_{on}$	$I_G=40mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	7	$\mu s$
$t_{off}$				50	

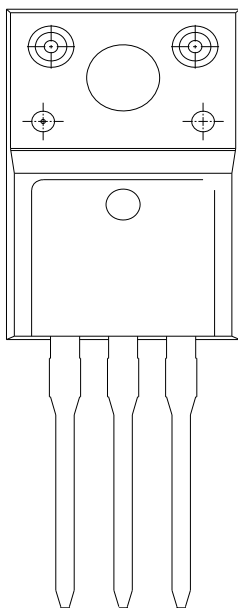
**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=22.5A t_p=380\mu s$	$T_j=25$	1.5	V
$V_{TO}$	Threshold voltage	$T_j=125$	0.77	V
$R_D$	Dynamic resistance	$T_j=125$	30	m
$I_{DRM}$ $I_{RRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25$ $T_j \hat{A}$	10	$\mu A$

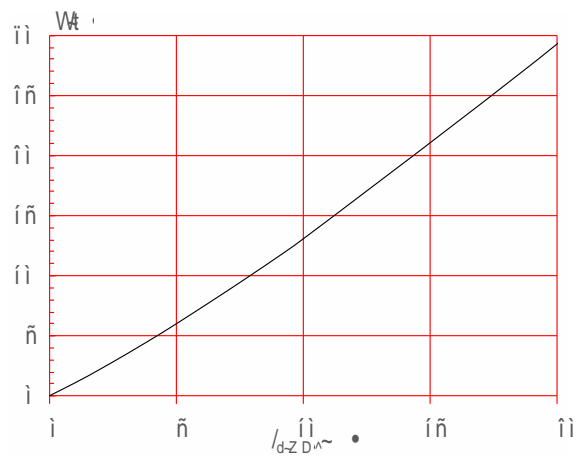
ORDERING INFORMATION



MARKING



**FIG.1:** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature

d

FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards TT



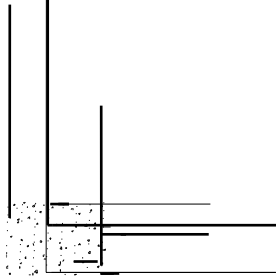
**ORDERING INFORMATION**

Order code	Voltage V <sub>DRM</sub> /V <sub>RRM</sub> (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
<b>JST16F-1000CW</b>	<b>1000</b>	<b>35</b>	<b>TO-220F(Ins)</b>	<b>50</b>	<b>Tube</b>

**Document Revision History**

Date	Revision	Changes
May.18, 2023	A.1.0	Last updated
Oct.13, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



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